NSN 5962-00-137-5005

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View Online at https://aerobasegroup.com/nsn/5962-00-137-5005
Body Length:
0.390 inches
Body Width:
0.390 inches
Body Height:
0.070 inches
Maximum Power Dissipation Rating:
307.2 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and bipolar and negative outputs and unipolar and programmable and programmed
and w/enable and wire-or outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-20.0 volts power source and 8.3 volts power source
Time Rating Per Chacteristic:
900.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
09128-d34005544 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
30 flat leads
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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